IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In repatent application of

Masaki HASHIMURA, et al!

Serial No.:

10/601,310

2812

Filing Date:

June 23, 2003

Examiner:

Unknown

For:

SEMICONDUCTOR ELEMENT AND METHOD FOR PRODUCING THE

Group Art Unit:

SAME

INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.99 and pursuant to Applicants' duty of disclosure under 37 CFR §1.56, Applicants respectfully bring the following documents cited in the Chinese Office Action and listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which Applicants are aware.

In compliance with the concise explanation requirement under 37 CFR §1.98(a)(3) for foreign language documents, Applicants enclose herewith a copy of the Chinese Office Action citing such documents, together with an English-language version (if not already included) of the Search Report indicating the degree of relevance found by the foreign office. Further, English-language Abstracts are attached to the foreign references.

I hereby certify that each item of information contained in this Information Disclosure Statement was the first citation of that item by a foreign patent office in a counterpart foreign application, which occurred not more than three months prior to the filing of this statement.

Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 50-0481.

Respectfully submitted,

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